

# Schottky Diode

## **SS25**

50V / 2A

# DATASHEET

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OEM – General Semiconductor

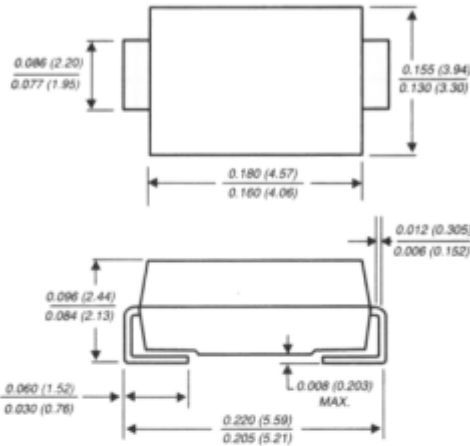
Source: General Semiconductor Databook 1998

# SS22 THRU SS26

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 60 Volts    Forward Current - 2.0 Amperes

DO-214AA



Dimensions in inches and (millimeters)

### FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Low profile package
- ◆ Built-in strain relief
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage high frequency inverters, free wheeling, and polarity protection applications
- ◆ Guardring for overvoltage protection
- ◆ High temperature soldering guaranteed: 250°C/10 seconds at terminals



### MECHANICAL DATA

**Case:** JEDEC DO-214AA molded plastic body

**Terminals:** Solder plated, solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Weight:** 0.003 ounce, 0.093 gram

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	SS22	SS23	SS24	SS25	SS26	UNITS
Device marking code		S2	S3	S4	S5	S6	
Maximum repetitive peak reverse voltage	VRRM	20	30	40	50	60	Volts
Maximum RMS voltage	VRMS	14	21	28	35	42	Volts
Maximum DC blocking voltage	VDC	20	30	40	50	60	Volts
Maximum average forward rectified current at T <sub>L</sub> (SEE FIG. 1)	I(AV)	2.0					Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	50.0					Amps
Maximum instantaneous forward voltage at 2.0A (NOTE 1)	V <sub>F</sub>	0.50			0.70		Volts
Maximum DC reverse current (NOTE 1) T <sub>A</sub> =25°C at rated DC blocking voltage T <sub>A</sub> =100°C	I <sub>R</sub>	0.4			10.0		mA
Maximum thermal resistance (NOTE 2)	R <sub>θJA</sub>	75.0					°C/W
	R <sub>θJL</sub>	17.0					
Operating junction temperature range	T <sub>J</sub>	-65 to +125			-65 to +150		°C
Storage temperature range	T <sub>STG</sub>	-65 to +150					°C

**NOTES:**

- (1) Pulse test: 300µs pulse width, 1% duty cycle
- (2) P.C.B. mounted with 0.2 x 0.2" (5.0 x 5.0mm) copper pad areas

**RATINGS AND CHARACTERISTIC CURVES SS22 THRU SS26**

